2SB1252

Silicon PNP epitaxial planar type darlington

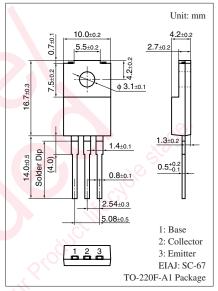
For power amplification

Features

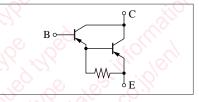
- Optimum for 35 W Hi-Fi output
- \bullet High forward current transfer ratio h_{FE}
- Low collector-emitter saturation voltage $V_{CE(sat)}$
- Full-pack package which can be installed to the heat sink with one screw.

Absolute Maximum Ratings $T_C = 25^{\circ}C$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V _{CBO}	-120	v
Collector-emitter voltage (Base open)	V _{CEO}	-100	V
Emitter-base voltage (Collector open)	V _{EBO}	-5	V
Collector current	I _C	-5	А
Peak collector current	I _{CP}	-8	А
Collector power	P _C	45	W
dissipation $T_a = 25^{\circ}C$		2	i.
Junction temperature	Tj	150	°C
Storage temperature	T _{stg}	-55 to +150	°C



Internal Connection



Electrical Characteristics $T_c = 25^{\circ}C \pm 3^{\circ}C$

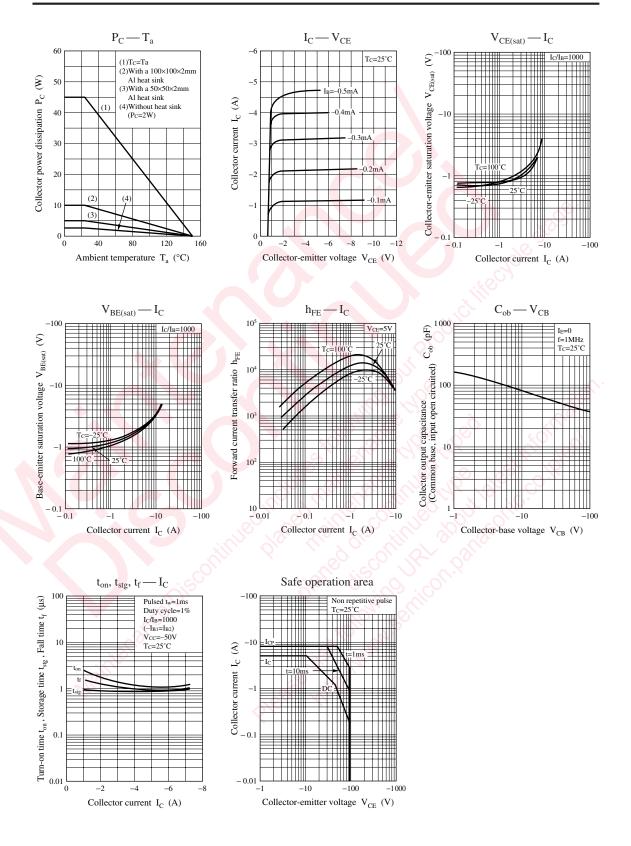
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = -30$ mA, $I_{\rm B} = 0$	-100	25		V
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = -120 \text{ V}, I_E = 0$	2	-	-100	μΑ
Collector-emitter cutoff current (Base open)	I _{CEO}	$V_{CE} = -100 \text{ V}, I_{B} = 0$			-100	μΑ
Emitter-base cutoff current (Collector open)	I _{EBO}	$V_{EB} = -5 V, I_C = 0$			-100	μΑ
Forward current transfer ratio	h _{FE1}	$V_{CE} = -5 V, I_C = -1 A$	2000			_
	h _{FE2} *	$V_{CE} = -5 V, I_C = -4 A$	5000		30 0 0 0	
Collector-emitter saturation voltage	V _{CE(sat)}	$I_{\rm C} = -4$ A, $I_{\rm B} = -4$ mA			-2.5	V
Base-emitter saturation voltage	V _{BE(sat)}	$I_{\rm C} = -4$ A, $I_{\rm B} = -4$ mA			-3.0	V
Transition frequency	f _T	$V_{CE} = -10 \text{ V}, I_C = -0.5 \text{ A}, f = 1 \text{ MHz}$		20		MHz
Turn-on time	t _{on}	$I_{C} = -4 \text{ A}, I_{B1} = -4 \text{ mA}, I_{B2} = 4 \text{ mA}$		1.0		μs
Storage time	t _{stg}	$V_{\rm CC} = -50 \text{ V}$		0.8		μs
Fall time	t _f			1.0		μs

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

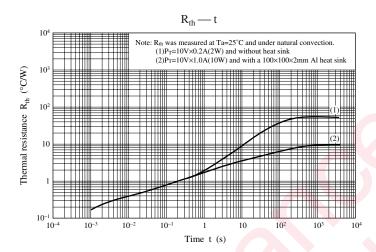
2. *: Rank classification

Rank	Q	Р
h _{FE2}	5000 to 15000	8000 to 30000

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